



Effect of vanadium admixing on the surface structure of TiO₂(110) under non-oxidizing conditions



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ABSTRACT

Single crystalline Ti + V mixed oxide layers have been prepared by doping vanadium into TiO₂(110) thin films on TiO₂(110) single crystal substrates with a Ti + Ta mixed oxide interlayer between the film and the substrate. The interlayer prevents the diffusion of vanadium into the substrate and also the diffusion of Ti³⁺ between substrate and overlayer. Mixing vanadium into the TiO₂ lattice increases the reducibility of the host oxide as concluded from an appreciable degree of reduction produced by comparatively mild annealing. A high density of bridging oxygen vacancies was identified at the surface of films with a low vanadium content (2%) while a (1 × 2) reconstruction as also known for massively reduced TiO₂(110) was observed for layers with 8% of vanadium. Studies of methanol adsorption indicate that the vanadium atoms are mostly located below the surface since there is no indication of a vanadium-methanol interaction. We provide evidence that the reducibility of the vanadium ions in the thin film is higher than that of the titanium ions and we suggest that this is the origin of the increased reducibility of the mixed oxide.

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1. Introduction

Dopants can have a substantial effect on the catalytic properties of an oxide as shown by theoretical and experimental studies [1–4]. Already half a century ago it was shown that Ni-doped MgO powder samples are more active for N₂O decomposition than pure MgO [5]. Dopant atoms modify the properties of the atoms in the surrounding crystal volume. They may affect the crystal structure and may act as sources or sinks for electron charge which may strongly affect the catalytic properties [6–9]. Well-defined single crystalline models of real-life catalysts are well suited to study such effects at an atomic level due to the reduced complexity of such systems [4,10]. For instance, the activation of oxygen to a superoxo species by molybdenum atoms in CaO(001) was studied in detail with STM (scanning tunneling microscopy) and DFT (density functional theory) showing that a charge transfer involving the molybdenum atoms is responsible for this activation [8]. Dopants can also donate charge to deposited clusters, thereby changing their structure and probably also their catalytic properties as shown for the case of gold clusters on Mo doped CaO(100) [9]. The action of dopants is a rather general aspect of catalytic processes at surfaces and therefore an ongoing research activity in this field may be expected.

While TiO₂ single crystal surfaces are used mainly as supports in model catalytic studies [11–14], the modification of TiO₂ by dopants

with the aim to enhance its catalytic/photocatalytic properties has also been investigated [15–17]. TiO₂ powder with cationic alkaline metal dopants (Li, Na, K and Cs) was found to catalyze acetone oligomerization [18], and anion dopants such as N and F were shown to affect the photo-catalytic efficiency of TiO₂ [15,19]. Nitrogen atoms doped into rutile and anatase single crystals with ion implantation methods were reported to promote the formation of oxygen vacancies [19], while Cr-doping of TiO₂(110) by calcination with Cr₂O₃ powder was found to increase the rate of surface oxygen vacancy formation [20]. In this work, we focus on the influence of a vanadium admixture on the properties of rutile TiO₂(110). A problem for the preparation of a vanadium admixture into TiO₂(110) is the high speed of vanadium diffusion in TiO₂ at elevated temperature (>600 K), which leads to the loss of vanadium into the bulk of the TiO₂ single crystal if the vanadium admixture is prepared by vanadium deposition at the surface or admixture in near-surface regions [21,22]. In order to circumvent the vanadium diffusion problem, we have developed a recipe for the preparation of TiO₂(110) layers on TiO₂(110) single crystal substrates with a Ta + Ti mixed oxide diffusion barrier between the film and the substrate as described in a recent publication [23]. The diffusion barrier does not just block the diffusion of Ti³⁺ ions as discussed in reference [23], but also the diffusion of vanadium ions [24].

2. Experimental methods

The experiments were carried out with two different UHV systems. Both systems were equipped with ion guns for sample cleaning via

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Ar⁺ ion sputtering, LEED (low energy electron diffraction) systems to check the surface order, electron beam evaporators (manufactured by Focus GmbH, Germany) for the deposition of vanadium, titanium and tantalum, and quartz microbalances for the calibration of the metal deposition rates.

High-resolution XPS spectra were recorded with a system located at the UE52-PGM-PES beamline of the BESSY II electron storage ring. The V 2p and Ti 2p XPS (X-ray photoelectron spectroscopy) data were recorded with a R4000 hemispherical electron energy analyzer (manufactured by VG-Scienta) employing photons with an energy of 630 eV. At a photon energy of 630 eV the surface sensitivity of V 2p and Ti 2p spectra is rather high [the electron IMFP (Inelastic mean free path) in TiO₂ is in the range of 5–6 Å according to the QUASES-IMFP program (downloadable from <http://www.quases.com>)]. Part of the spectra were recorded with an electron exit angle of 80° with respect to the surface normal which leads to an even higher surface sensitivity. The energy scale was calibrated by positioning the Au 4f_{7/2} level in a spectrum of a gold sheet at its literature value of 84 eV [25].

TPD (temperature programmed desorption) and STM (scanning tunneling microscopy) data were recorded in another UHV system which was additionally equipped with an EA125 electron energy analyzer (Omicron) for XPS. The room-temperature STM system was also manufactured by Omicron (model: STM1). STM images were measured with a bias voltage of 2.0 V and a tunneling current of 0.1 nA. The WSxM software was used to process the images [26]. The quadrupole mass spectrometer (Thermo Systems) used for TPD was mounted in a differentially pumped housing with a small (4 mm diameter) entrance opening (Feulner cup) [27]. During TPD measurements, the sample was positioned directly in front of this opening which significantly decreases the probability that gas molecules desorbing from the sample holder reach the mass spectrometer. TPD spectra with methanol as the probe molecule were recorded to test the reactivity of the mixed oxide. In these experiments 50 L (1 L = 1 × 10^{−6} Torr·s) of methanol were dosed at room temperature and the spectra were recorded with a constant heating rate of 0.5 K s^{−1}. Contributions of methanol to the spectra of masses 15 (methane), 18 (water) and 30 (formaldehyde) were subtracted prior to plotting according to $I_{\text{plotted}}^{\text{compound}} = I_{\text{raw}}^{\text{compound}} - C_{\text{compound}}^{\text{methanol, mass 31}} \cdot I_{\text{raw}}^{\text{methanol, mass 31}}$, with the factor $C_{\text{compound}}^{\text{methanol, mass 31}}$ being calculated from the mass fragmentation pattern of methanol and sensitivity factors published by the manufacturer of the mass spectrometer, and I denoting intensities.

The TiO₂(110) single crystal substrates were prepared by sputtering and annealing cycles consisting of sputtering with Ar⁺ ions (1 keV, 5 μA) for 30 min at room temperature followed by annealing at 970 K in vacuum. These cycles were repeated until LEED images exhibited sharp spots with a low background intensity and XPS spectra did not show recognizable peaks other than those of TiO₂. After the initial preparation, the crystals had a light blue color which grew darker in the course of the experiments due to the annealing cycles required in further preparation steps. We note that this did not have a significant influence on the quality of the layers due to the presence of the Ti + Ta diffusion blocking barrier.

After substrate preparation, the Ti + Ta blocking layer (Ti_{0.8}Ta_{0.2}O₂, 30 Å thick) was prepared by co-deposition of Ta and Ti in an oxygen ambient atmosphere (1 × 10^{−6} mbar) at a sample temperature of 800 K, following a recipe recently developed in our research group [23]. Subsequently, a TiO₂(110) film (100 Å thick) was grown on the blocking layer by deposition of Ti under the same conditions as those employed for the preparation of the blocking layer. Vanadium was added to the TiO₂(110) layer either by vanadium co-deposition during the growth of the TiO₂(110) layer or by deposition of vanadium onto the TiO₂(110) in O₂. The final step was to anneal the sample in ultrahigh vacuum (2 × 10^{−10} mbar) at 800 K for 10 min. Both ways of vanadium doping lead to essentially identical Ti + V mixed oxide layers since during annealing in vacuum vanadium dilutes into the layer due to its high diffusion speed at 800 K. The vanadium admixture concentrations C

given in this publication are ratios of cross-section weighted intensities calculated from XPS spectra: $C = I_{V\ 2p} / (I_{V\ 2p} + I_{Ti\ 2p})$.

3. Results and discussions

3.1. Surface structure of TiO₂(110) mixed with vanadium

The surface structure of the mixed oxide layers was studied with STM and LEED. Fig. 1 shows STM images of a TiO₂(110) thin film without, with 2% and with 8% of vanadium. Flat terraces with sizes of tens of nm are found on the (1 × 1) surface of the pure TiO₂ thin film after annealing in vacuum at 800 K for 10 min. When 2% of vanadium is introduced, rod-like structures along [0 0 1] (2 nm to 20 nm long) appear on the flat terraces. Apart from these structures, the surface has the typical (1 × 1) TiO₂(110) structure as shown in the inset in Fig. 1(b) in which a square and a circle mark two different bright spots on the dark O rods. Protrusions of the type marked by a square are usually assigned to bridging oxygen vacancies (BOVs) [28]. The density of such structures is about 15% per unit cell, higher than the 7% found for the TiO₂(110) thin film surface after annealing in vacuum at 800 K for 10 min [23]. The bright spot marked by a circle is attributed to a hydroxyl group resulting from the dissociation of water (from the residual gas atmosphere) at the surface. The rod-like structures centered above the bright Ti rods are about 1.2 nm wide and 0.3 nm high, which is identical to what has been reported for the “Ti₂O₃ rods” at (1 × 2) reconstructed surfaces of strongly reduced TiO₂(110) [29].

When more vanadium (8%) is introduced into the TiO₂ thin film, more and longer rods along [0 0 1] show up together with cross-links along [110] as shown in Fig. 1(c). The smallest distance between two neighboring rods is about 1.3 nm, which is twice the (1 × 1) lattice parameter (0.65 nm) along [110]. This periodicity is reflected in the LEED pattern in Fig. 1(d) by (1 × 2) type superstructure spots. Distances larger than 1.3 nm between two neighboring rods are responsible for the diffuse intensity bridges between the regular TiO₂(110) spots along [110]. The uniform appearance of the rods [see inset in Fig. 1(c)] is a vague indication that they contain just one type of metal ions, either vanadium or titanium. The STM images shown here are very similar to STM images of heavily reduced (1 × 2) reconstructed TiO₂(110) surfaces [29–31], which is a good indication that the rods seen in the STM images in Fig. 1 just contain titanium.

The (1 × 2) reconstruction of regular TiO₂(110) (without vanadium) results from a strong reduction of the sample. It may be prepared by high temperature annealing in vacuo at temperatures in the range of 1300 K [29–31]. In our case of TiO₂(110) with dissolved vanadium, mild annealing at 800 K for 10 min was sufficient to prepare this reconstruction while it did not form on the surface of the vanadium free TiO₂(110) after the same annealing treatment (see Fig. 1). Apparently the (1 × 2) reconstruction of the Ti + V mixed oxide layer surface is a consequence of the vanadium admixture to the TiO₂(110) thin film.

3.2. Origin of the increased reducibility

Fig. 2 displays Ti 2p and V 2p core level XPS spectra of TiO₂(110) with admixed vanadium. Spectra of an oxidized surface (annealed in 2 × 10^{−6} mbar O₂ at 850 K for 1 min) are compared to spectra of a reduced surface (annealed in vacuo at 850 K for 5 min). At a photon energy of 630 eV the information depth of V 2p and Ti 2p spectra is 5–6 Å for 0° detection angle and only ~2 Å for a detection angle of 80° which means that in the latter case the spectra are strongly dominated by electrons from the topmost surface layer whereas electrons from deeper layers contribute more in the spectra recorded at 0°. Annealing in oxygen led to band bending which shifted all levels by 0.5 eV to lower binding energy. Therefore the energy scales in the graphs showing spectra of oxidized surfaces were shifted such that the Ti 2p binding energies were 459.0 eV like in the spectra of reduced surfaces.

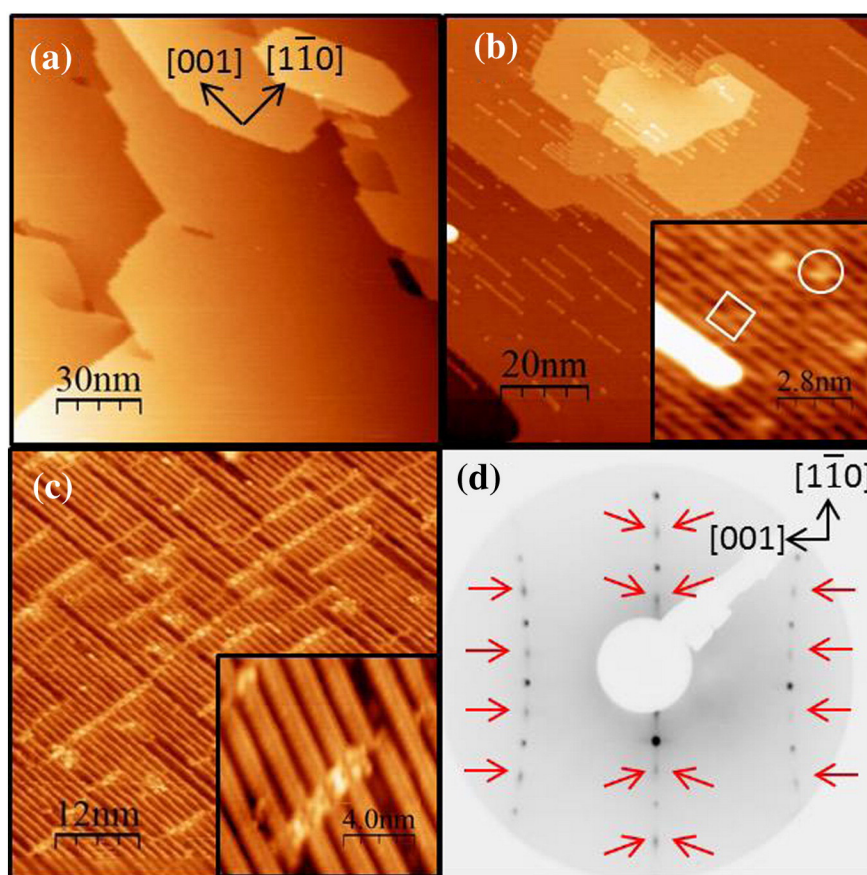


Fig. 1. (a) STM image of a $\text{TiO}_2(110)$ thin film without vanadium. (b) STM image of a $\text{TiO}_2(110)$ thin film with 2% of vanadium. The inset ($8 \text{ nm} \times 8 \text{ nm}$) shows the atomically resolved (1×1) surface with an oxygen vacancy marked by a square and a hydroxyl group by a circle. (c) STM image of a $\text{TiO}_2(110)$ thin film with 8% of vanadium. The inset ($12 \text{ nm} \times 12 \text{ nm}$, somewhat distorted due to thermal drift) shows an excerpt of the image. (d) LEED pattern of the sample whose STM image is shown in panel (c). Red arrows mark the spots of the (1×2) superstructure. All layers were annealed in vacuo for 10 min at 800 K prior to recording the STM images. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

The Ti 2p and V 2p peaks were fitted by two or three mixed Gaussian-Lorentzian functions. Binding energies close to the literature values were obtained from the fits for Ti (Ti^{4+} , Ti^{3+}) and V (V^{5+} , V^{4+}

and V^{3+}) [32–35]. Results are listed in Table 1. The numbers show that the concentration of vanadium at the oxidized surface (65%, 0°) is much higher than at the reduced surface (23%, 0°), and that in the

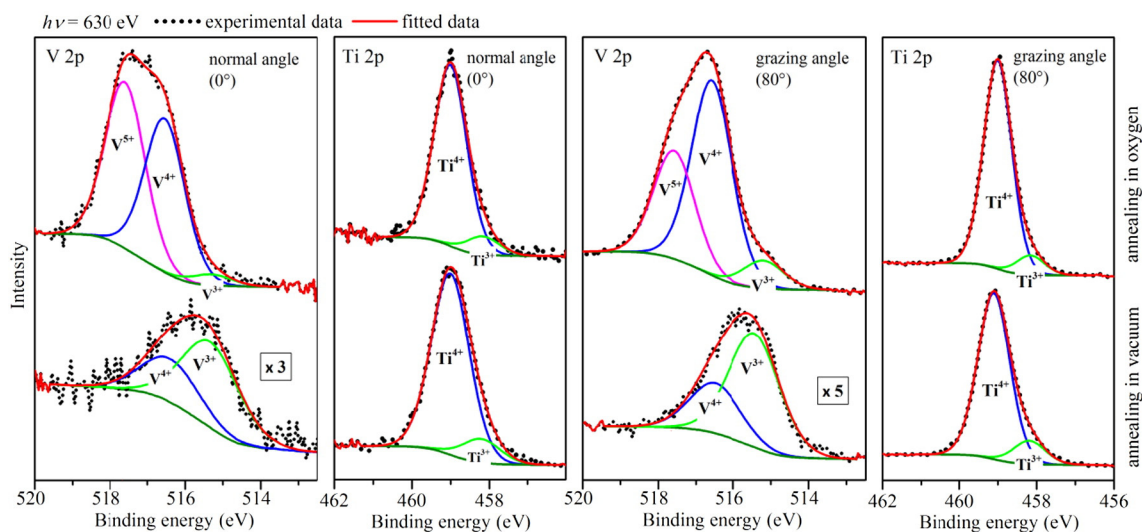


Fig. 2. V 2p and Ti 2p core level XPS spectra of a $\text{TiO}_2(110)$ layer with admixed vanadium (concentrations are listed in Table 1). The spectra at the top were recorded after annealing the layer in 2×10^{-6} mbar of O_2 at 850 K for 1 min; the ones at the bottom were recorded after annealing in vacuum at 850 K for 5 min. The photon energy was 630 eV for all spectra. Electron detection angles of 0° and 80° with respect to the surface normal were employed. All spectra were fitted by two or three Gaussian-Lorentzian functions with a Shirley-type background subtracted before fitting. The count rates in the V 2p spectra of the reduced surfaces were multiplied by factors of 3 and 5, respectively, in order to compensate for the low emission intensities.

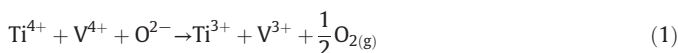
Table 1

Relative concentrations of vanadium and titanium ions with different oxidation states as obtained from the spectra shown in Fig. 2. The binding energies listed in this table result from peak fitting of the spectra.

Oxidation state	V ⁵⁺	V ⁴⁺	V ³⁺	Sum(V)	Ti ⁴⁺	Ti ³⁺	Sum(Ti)
Binding energy (eV)	517.6	516.5	515.3		459.0	458.2	
Annealing in O ₂							
% (80°)	22	40	5	67	30	3	33
% (0°)	33	30	2	65	32	3	35
Annealing in vacuum							
% (80°)	0	4	8	12	77	11	88
% (0°)	0	8	15	23	68	9	77

case of the reduced surface, the concentration of vanadium at the surface is lower than below it as concluded from the concentrations obtained for different detection angles (23% for 0° vs 12% for 80°). This means that the vanadium tends to agglomerate at the surface in case of annealing in oxygen while reduction by annealing in vacuum leads to a situation where the vanadium ions avoid the surface. The overall vanadium concentration was less in the layers whose surface STM images are shown in Fig. 1, which is probably the reason why the images do not exhibit any clear indication of the presence of vanadium atoms at the surface at all.

Most of the vanadium atoms have a V⁴⁺ or V⁵⁺ oxidation state after annealing in oxygen while there is no V⁵⁺ in the reduced oxide. The concentration ratio [V³⁺]/[V⁴⁺] for the reduced oxide is ~2 for both detection angles. The corresponding concentration ratio for the titanium ions ([Ti³⁺]/[Ti⁴⁺]) is 0.13–0.14 which shows that reduction affects the vanadium ions much more than the titanium ions. Table 1 shows that the Ti³⁺ and V³⁺ concentrations in the reduced layer are not too different (some percent difference should be not be taken too serious since the error margin for the Ti³⁺ concentrations is surely significant since the Ti³⁺ peaks are just weak shoulders in the Ti 2p structures in Fig. 2) which indicates that the reduction may occur via the following reaction:



as opposed to the mechanism for a layer without vanadium:



The reduction according to Eq. (1) would produce Ti³⁺ and V³⁺ in equal amounts, in rough agreement with the numbers listed in Table 1. We note that the Ti 2p spectra of the reduced mixed oxide layer in Fig. 2 are similar to spectra measured for a regular TiO₂(110) (1 × 2) surface [12,32,36], consistent with similar degrees of reduction.

The fourth atomic ionization energies are 46.71 eV for vanadium (V³⁺ → V⁴⁺) and 43.08 eV for titanium (Ti³⁺ → Ti⁴⁺) [37,38], which is a hint that the reduction of vanadium in TiO₂ might cost less energy than the reduction of Ti which would lead to an enhanced reducibility of TiO₂ with admixed vanadium, as experimentally observed. This simple picture may be somewhat reasonable since vanadium ions occupy the same lattice sites as titanium ions according to a recent photoelectron diffraction study [24]. We note that VO₂ (rutile structure) has a bulk oxygen vacancy formation energy of 3.53 eV [39], somewhat lower than the corresponding value (≥4.35 eV) for TiO₂ [40], which is a further indication that a reduction process involving vanadium ions is energetically preferred.

The formation energies of BOVs at the (110) surfaces of regular and V-doped TiO₂ have recently been calculated by Kim et al. with DFT slab calculations [41]. In their model a vanadium atom replaces a 5-fold coordinated surface Ti atom. According to their results, the energy to remove a certain bridging oxygen atom from the neighborhood of a 5-fold coordinated V atom is 3.37 eV which is lower than the energy of 3.72 eV for pure TiO₂(110). While this model is not strictly applicable

to the current situation, since the vanadium atoms prefer to stay below the very surface in the case of a reduced mixed oxide, it is nevertheless another indication that the introduction of vanadium into TiO₂ may result in an increased reducibility. The observation that vanadium prefers a location below the surface is in accord with the results of a calculation by Asaduzzaman and Krueger who found that vanadium atom prefer substitutional sub-surface sites over surface sites [42].

Nitrogen and chromium doping also affect the defect density in TiO₂(110) [20,43]. A (1 × 2) reconstruction was observed in the case of nitrogen doping by implantation. It was assumed that the higher charge of nitrogen (N³⁻) relative to that of oxygen (O²⁻) results in oxygen vacancies to maintain charge neutrality [19]. Lattice stress minimization and again charge neutrality were assumed to be responsible for an enhanced concentration of oxygen vacancies in the case of doping with chromium [20]. In the here-discussed case of a vanadium admixture, the lattice stress will be rather small since the ionic radii of V³⁺ and V⁴⁺ are close to those of their titanium counterparts [44], and V⁵⁺ does probably not exist in significant concentrations below the surface [24]. Therefore we assume (as discussed before) that a lower energy for the reduction of V⁴⁺ relative to that of Ti⁴⁺ is responsible for the increased reducibility in the present case.

3.3. Reactivity test with methanol adsorption

The chemical activity of the mixed oxide layers was examined with TPD using methanol as the probe molecule. Fig. 3(a) displays TPD spectra recorded for methanol adsorbed on a layer with 2% of vanadium. Methanol (*m/z* = 31) has major desorption peaks at 350 K and 680 K. Water (*m/z* = 18) desorbs at 500 K, and formaldehyde (*m/z* = 30) desorption is found at 680 K. There is also a weak methane signal (*m/z* = 15) at about 700 K while ethylene (*m/z* = 27) intensity higher than the noise level of the spectrometer is not observed. These results are similar to results reported for a TiO₂(110) layer without vanadium except that the intensities are somewhat different [23].

Formaldehyde TPD spectra of (*m/z* = 30) for different vanadium concentrations are shown in Fig. 3(b). The intensity of the peak at 680 K is highest for 2% of vanadium and decreases when the vanadium concentration is increased beyond this level or decreased below it. The amount of formaldehyde produced by a film with 7% of vanadium is approximately the same as the amount produced by the pure TiO₂ thin film while the amount is near to zero when the layer contains 12% of vanadium.

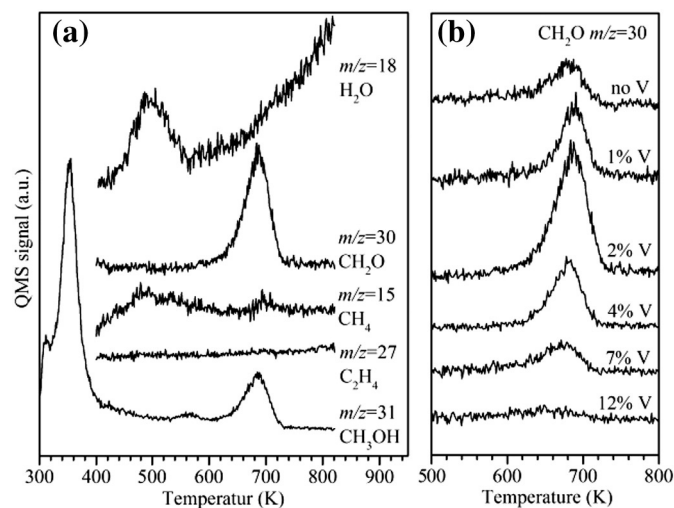


Fig. 3. (a) TPD spectra of 50 L of methanol adsorbed at room temperature onto a TiO₂(110) layer with 2% of vanadium. (b) TPD spectra (mass 30) of methanol on a TiO₂(110) thin film with different vanadium concentrations (0%, 1%, 2%, 4%, 7% and 12%).

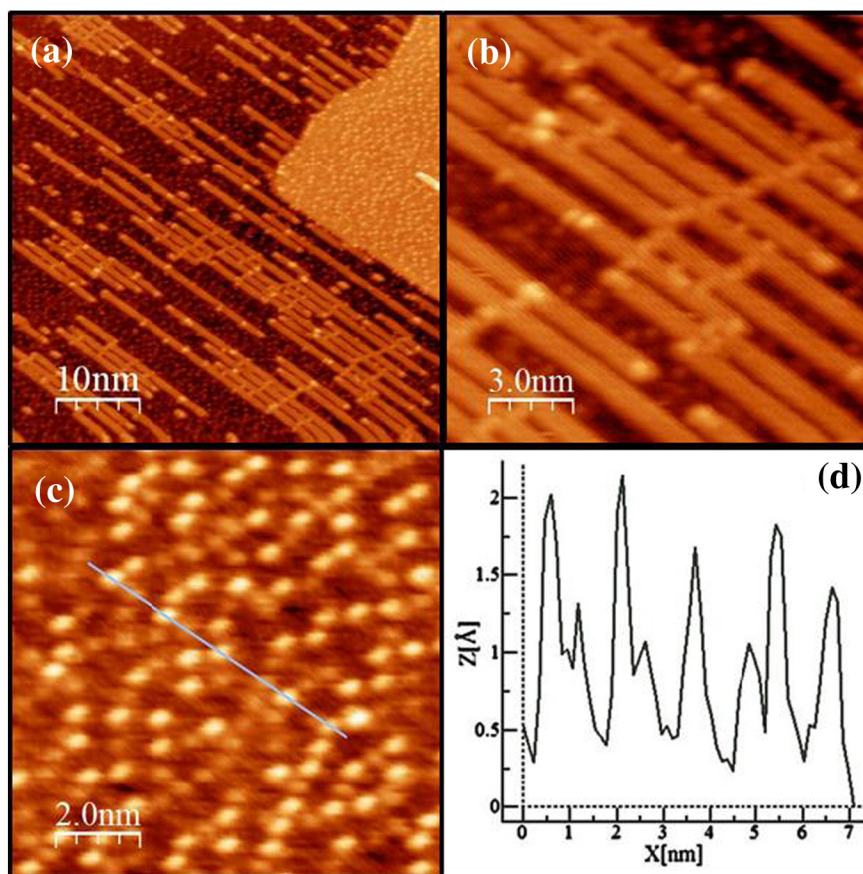


Fig. 4. (a) STM image of a $\text{TiO}_2(110)$ film with 2% of vanadium exposed to 50 L of methanol at 300 K. Prior to scanning the sample was flashed to 400 K to desorb molecularly adsorbed methanol. (b) Part of image (a) containing mainly (1×2) rods. (c) Part of image (a) showing an area without (1×2) rods. (d) Height profile measured along the line in image (c).

According to TPD studies of methanol on $\text{TiO}_2(110)$, the desorption of formaldehyde at 680 K is related to methoxy groups bound to BOV sites [23,45,46]. The large amount of formaldehyde desorbing from the film with 2% of vanadium reflects the high concentration of BOV sites at the surface of this film, which is about 15% as estimated from the STM image in Fig. 1(b). The BOV density at the surface of the layer without vanadium is only 7% which leads to the smaller intensity of the formaldehyde desorption peak in Fig. 3(b). The surface of the layer with 12% of vanadium is largely covered with the (1×2) reconstruction. There are not many BOVs but many “ Ti_2O_3 ” rods which are apparently chemically inactive. The TPD data do only exhibit structures which are also known for methanol on regular $\text{TiO}_2(110)$ without vanadium which is a strong indication that there is no direct methanol–vanadium interaction, supporting the conclusion obtained from the XPS measurements that vanadium atoms are mostly located below the surface.

STM images recorded after adsorption of 50 L of methanol at 300 K provide further insight into the chemical activity of the mixed oxide layer. Methoxy groups bound to BOVs and hydroxyl groups were the only methanol-related species at the surface since it was flashed to 400 K before the images were recorded. The images exhibit only a few methanol-induced protrusions on the (1×2) rods [see Fig. 4(b)], indicating that the rods are essentially inactive for formaldehyde production, in agreement with the conclusions drawn from the TPD experiments. Fig. 4(c) shows that the area between the rods is densely covered with methanol related species. The height profile in shown Fig. 4(d) reveals species with two different heights (0.6 Å and 1.5 Å) which, following a comparison with literature values [28,47–49], are attributed to hydroxyl and methoxy groups, respectively. The density of the hydroxyl/methoxy groups is about 15% relative to the density of surface unit cells which is the same as the density of BOVs found for

the film doped with 2% of vanadium, which gave the highest yield of formaldehyde in the TPD experiments.

4. Conclusions

We have successfully prepared Ti + V mixed oxide layers with the vanadium ions locked in the layers by a diffusion blocking barrier between the $\text{TiO}_2(110)$ single crystal substrate and the overlayer. We found that the vanadium atoms prefer sub-surface sites in reduced layers, while vanadium concentrates at the surface when the layers are annealed in oxygen. The presence of vanadium ions increases the reducibility of the layers which leads to a high density of reduction related features at the surface even after a rather mild annealing at 800 K for some minutes. When a small amount of vanadium (e.g. 2%) is introduced into a layer, a high density of BOVs is produced by annealing at 800 K for some minutes. These BOVs are responsible for a large amount of formaldehyde produced by annealing a methanol covered surface to 680 K. When more vanadium ($\geq 8\%$) is dissolved in the layer, annealing at 800 K produces a (1×2) reconstruction with cross-links as known for heavily reduced $\text{TiO}_2(110)$. The (1×2) related rod-like surface structures appear to be largely inactive with respect to formaldehyde production. We assume that a smaller energy for the removal of oxygen from the vicinity of vanadium atoms in the $\text{TiO}_2(110)$ layer is responsible for the increased reducibility.

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